



DMN67D7L

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	5Ω @ V _{GS} = 10V	210mA

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- Power Management Functions

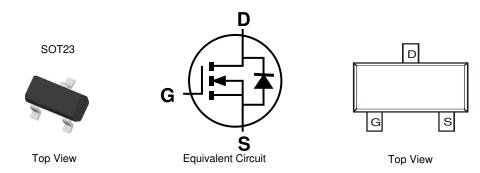
60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (C3)
- Terminal Connections: See Diagram
- Weight: 0.009 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN67D7L-7	SOT23	3,000/Tape & Reel
DMN67D7L-13	SOT23	10,000/Tape & Reel

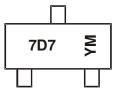
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



7D7 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

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Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	С		D	E		F	G		Н	I		J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	1	5	6	7	8	٩	\cap	N	П



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±40	V	
Continuous Drain Current (Note 6) V _{GS} = 10V		T _A = +25°C T _A = +85°C	ID	210 150	mA
Maximum Body Diode Forward Current (Note 6)		ls	500	mA	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	6)	I _{DM}	800	mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	340	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	376	°C/W
Total Power Dissipation (Note 6)		PD	570	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	224	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						·	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						•	
Gate Threshold Voltage	V _{GS(TH)}	0.8	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	р		3.2	7.5	Ω	$V_{GS} = 5.0V, I_D = 0.05A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.5	5.0	52	$V_{GS} = 10V, I_D = 0.5A$	
Diode Forward Voltage	V _{SD}		0.78	1.5	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS (Note 8)	·					·	
Input Capacitance	Ciss	—	22	_	pF		
Output Capacitance	C _{oss}	_	4.1	_	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	2.5	_	pF		
Gate Resistance	Rg	_	120	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qq	_	361				
Total Gate Charge (V _{GS} = 10V)	Qg	_	821	_	-0	$V_{DS} = 10V, I_D = 250mA$	
Gate-Source Charge	Q _{gs}		162		рС		
Gate-Drain Charge	Q _{gd}		116				
Turn-On Delay Time	t _{D(ON)}	<u> </u>	2.8				
Turn-On Rise Time	t _R	[_]	3.0		1	$V_{DD} = 30V, I_D = 0.2A,$	
Turn-Off Delay Time	t _{D(OFF)}	_	7.6		ns	$R_{L} = 150\Omega, V_{GEN} = 10V,$	
Turn-Off Fall Time	t _F	_	5.6	_		$R_{GEN} = 25\Omega$	

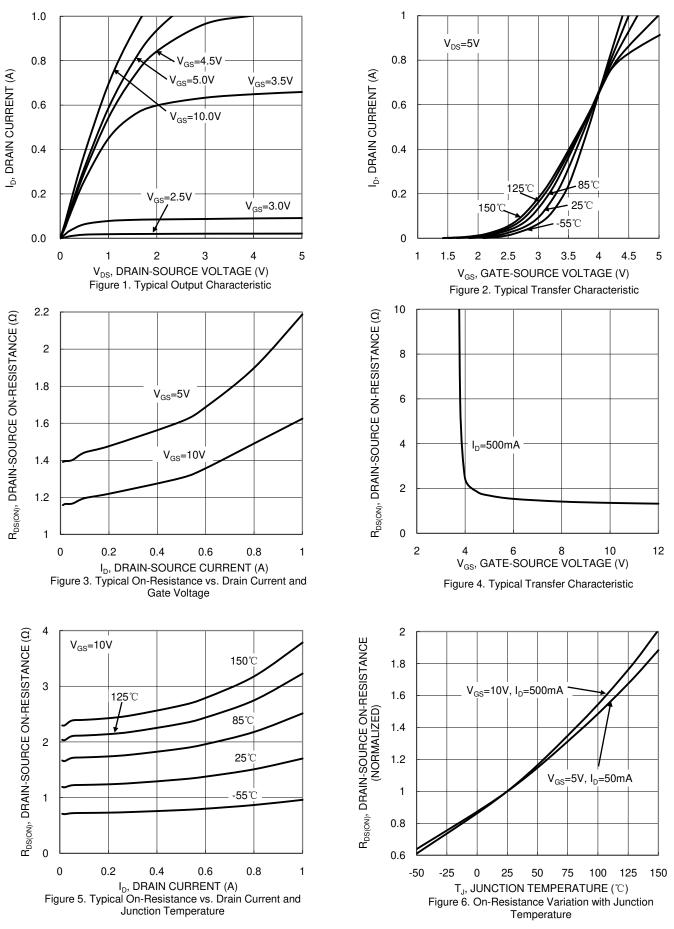
5. Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



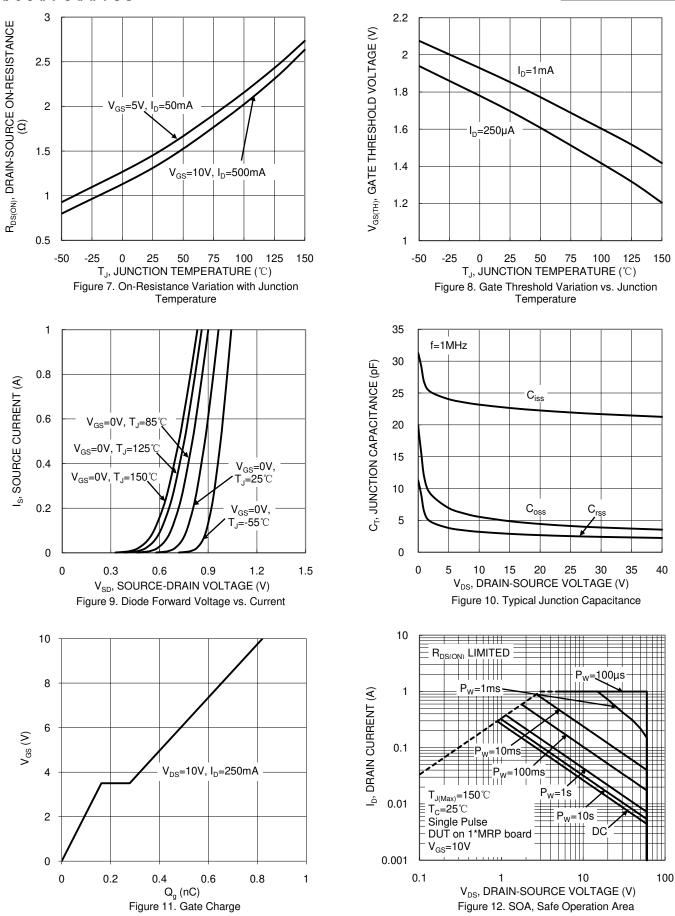




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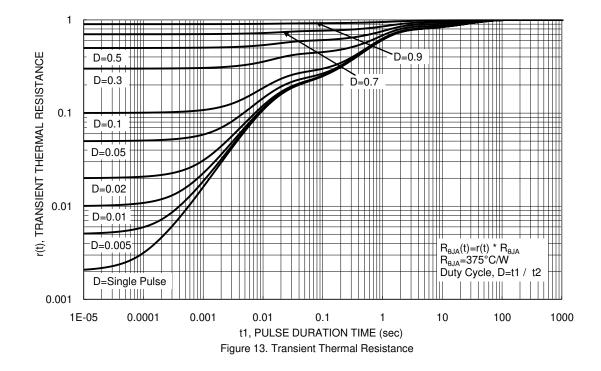


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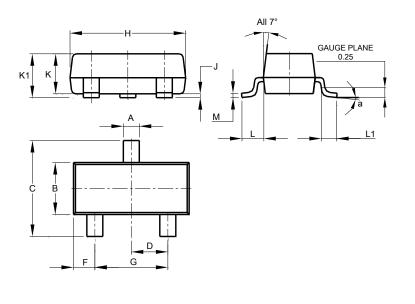




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

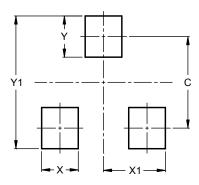
SOT23



SOT23								
Dim	Min	Min Max Typ						
Α	0.37	0.51	0.40					
в	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
H	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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